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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	72MHz
Connectivity	CANbus, EBI/EMI, I²C, IrDA, LINbus, SmartCard, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, LCD, POR, PWM, WDT
Number of I/O	50
Program Memory Size	2MB (2M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	384K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.8V
Data Converters	A/D 16x12b SAR; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-TQFP
Supplier Device Package	64-TQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm32gg11b510f2048gq64-b

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4.1.1 Absolute Maximum Ratings

Stresses above those listed below may cause permanent damage to the device. This is a stress rating only and functional operation of the devices at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability. For more information on the available quality and reliability data, see the Quality and Reliability Monitor Report at <http://www.silabs.com/support/quality/pages/default.aspx>.

Table 4.1. Absolute Maximum Ratings

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Storage temperature range	T _{STG}		-50	—	150	°C
Voltage on supply pins other than VREGI and VBUS	V _{DDMAX}		-0.3	—	3.8	V
Voltage ramp rate on any supply pin	V _{DDRAMPMAX}		—	—	1	V / μs
DC voltage on any GPIO pin	V _{DIGPIN}	5V tolerant GPIO pins ^{1 2 3}	-0.3	—	Min of 5.25 and IOVDD +2	V
		LCD pins ³	-0.3	—	Min of 3.8 and IOVDD +2	V
		Standard GPIO pins	-0.3	—	IOVDD+0.3	V
Total current into VDD power lines	I _{VDDMAX}	Source	—	—	200	mA
Total current into VSS ground lines	I _{VSSMAX}	Sink	—	—	200	mA
Current per I/O pin	I _{IOMAX}	Sink	—	—	50	mA
		Source	—	—	50	mA
Current for all I/O pins	I _{IOTALLMAX}	Sink	—	—	200	mA
		Source	—	—	200	mA
Junction temperature	T _J	-G grade devices	-40	—	105	°C
		-I grade devices	-40	—	125	°C
Voltage on regulator supply pins VREGI and VBUS	V _{VREGI}		-0.3	—	5.5	V

Note:

- When a GPIO pin is routed to the analog module through the APOR, the maximum voltage = IOVDD.
- Valid for IOVDD in valid operating range or when IOVDD is undriven (high-Z). If IOVDD is connected to a low-impedance source below the valid operating range (e.g. IOVDD shorted to VSS), the pin voltage maximum is IOVDD + 0.3 V, to avoid exceeding the maximum IO current specifications.
- To operate above the IOVDD supply rail, over-voltage tolerance must be enabled according to the GPIO_Px_OVTDIS register. Pins with over-voltage tolerance disabled have the same limits as Standard GPIO.

4.1.2 Operating Conditions

When assigning supply sources, the following requirements must be observed:

- VREGVDD must be greater than or equal to AVDD, DVDD and all IOVDD supplies.
- VREGVDD = AVDD
- DVDD \leq AVDD
- IOVDD \leq AVDD

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Note:						
1.	The minimum voltage required in bypass mode is calculated using R_{BYP} from the DCDC specification table. Requirements for other loads can be calculated as $V_{DVDD_min} + I_{LOAD} * R_{BYP_max}$.					
2.	VREGVDD must be tied to AVDD. Both VREGVDD and AVDD minimum voltages must be satisfied for the part to operate.					
3.	The system designer should consult the characteristic specs of the capacitor used on DECOUPLE to ensure its capacitance value stays within the specified bounds across temperature and DC bias.					
4.	VSCALE0 to VSCALE2 voltage change transitions occur at a rate of 10 mV / usec for approximately 20 usec. During this transition, peak currents will be dependent on the value of the DECOUPLE output capacitor, from 35 mA (with a 1 μ F capacitor) to 70 mA (with a 2.7 μ F capacitor).					
5.	When the CSEN peripheral is used with chopping enabled (CSEN_CTRL_CHOPEN = ENABLE), IOVDD must be equal to AVDD.					
6.	The maximum limit on T_A may be lower due to device self-heating, which depends on the power dissipation of the specific application. T_A (max) = T_J (max) - (θ_{TAJA} x PowerDissipation). Refer to the Absolute Maximum Ratings table and the Thermal Characteristics table for T_J and θ_{TAJA} .					

4.1.3 Thermal Characteristics

Table 4.3. Thermal Characteristics

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Thermal resistance, QFN64 Package	THE _A _J _A _QFN64	4-Layer PCB, Air velocity = 0 m/s	—	17.8	—	°C/W
		4-Layer PCB, Air velocity = 1 m/s	—	15.4	—	°C/W
		4-Layer PCB, Air velocity = 2 m/s	—	13.8	—	°C/W
Thermal resistance, TQFP64 Package	THE _A _J _A _TQFP64	4-Layer PCB, Air velocity = 0 m/s	—	33.9	—	°C/W
		4-Layer PCB, Air velocity = 1 m/s	—	32.1	—	°C/W
		4-Layer PCB, Air velocity = 2 m/s	—	30.1	—	°C/W
Thermal resistance, TQFP100 Package	THE _A _J _A _TQFP100	4-Layer PCB, Air velocity = 0 m/s	—	44.1	—	°C/W
		4-Layer PCB, Air velocity = 1 m/s	—	37.7	—	°C/W
		4-Layer PCB, Air velocity = 2 m/s	—	35.5	—	°C/W
Thermal resistance, BGA112 Package	THE _A _J _A _BGA112	4-Layer PCB, Air velocity = 0 m/s	—	42.0	—	°C/W
		4-Layer PCB, Air velocity = 1 m/s	—	37.0	—	°C/W
		4-Layer PCB, Air velocity = 2 m/s	—	35.3	—	°C/W
Thermal resistance, BGA120 Package	THE _A _J _A _BGA120	4-Layer PCB, Air velocity = 0 m/s	—	47.9	—	°C/W
		4-Layer PCB, Air velocity = 1 m/s	—	41.8	—	°C/W
		4-Layer PCB, Air velocity = 2 m/s	—	39.6	—	°C/W
Thermal resistance, BGA152 Package	THE _A _J _A _BGA152	4-Layer PCB, Air velocity = 0 m/s	—	35.7	—	°C/W
		4-Layer PCB, Air velocity = 1 m/s	—	31.0	—	°C/W
		4-Layer PCB, Air velocity = 2 m/s	—	29.5	—	°C/W
Thermal resistance, BGA192 Package	THE _A _J _A _BGA192	4-Layer PCB, Air velocity = 0 m/s	—	47.9	—	°C/W
		4-Layer PCB, Air velocity = 1 m/s	—	41.8	—	°C/W
		4-Layer PCB, Air velocity = 2 m/s	—	39.6	—	°C/W

4.1.10.4 High-Frequency RC Oscillator (HFRCO)

Table 4.15. High-Frequency RC Oscillator (HFRCO)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Frequency accuracy	f_{HFRCO_ACC}	At production calibrated frequencies, across supply voltage and temperature	TBD	—	TBD	%
Start-up time	t_{HFRCO}	$f_{HFRCO} \geq 19 \text{ MHz}$	—	300	—	ns
		$4 < f_{HFRCO} < 19 \text{ MHz}$	—	1	—	μs
		$f_{HFRCO} \leq 4 \text{ MHz}$	—	2.5	—	μs
Maximum DPLL lock time ¹	t_{DPLL_LOCK}	$f_{REF} = 32.768 \text{ kHz}$, $f_{HFRCO} = 39.98 \text{ MHz}$, $N = 1219$, $M = 0$	—	183	—	μs
Current consumption on all supplies	I_{HFRCO}	$f_{HFRCO} = 72 \text{ MHz}$	—	608	TBD	μA
		$f_{HFRCO} = 64 \text{ MHz}$	—	545	TBD	μA
		$f_{HFRCO} = 56 \text{ MHz}$	—	478	TBD	μA
		$f_{HFRCO} = 48 \text{ MHz}$	—	413	TBD	μA
		$f_{HFRCO} = 38 \text{ MHz}$	—	341	TBD	μA
		$f_{HFRCO} = 32 \text{ MHz}$	—	286	TBD	μA
		$f_{HFRCO} = 26 \text{ MHz}$	—	240	TBD	μA
		$f_{HFRCO} = 19 \text{ MHz}$	—	191	TBD	μA
		$f_{HFRCO} = 16 \text{ MHz}$	—	164	TBD	μA
		$f_{HFRCO} = 13 \text{ MHz}$	—	143	TBD	μA
		$f_{HFRCO} = 7 \text{ MHz}$	—	103	TBD	μA
		$f_{HFRCO} = 4 \text{ MHz}$	—	42	TBD	μA
		$f_{HFRCO} = 2 \text{ MHz}$	—	33	TBD	μA
		$f_{HFRCO} = 1 \text{ MHz}$	—	28	TBD	μA
		$f_{HFRCO} = 72 \text{ MHz}$, DPLL enabled	—	927	TBD	μA
		$f_{HFRCO} = 40 \text{ MHz}$, DPLL enabled	—	526	TBD	μA
		$f_{HFRCO} = 32 \text{ MHz}$, DPLL enabled	—	419	TBD	μA
		$f_{HFRCO} = 16 \text{ MHz}$, DPLL enabled	—	233	TBD	μA
		$f_{HFRCO} = 4 \text{ MHz}$, DPLL enabled	—	59	TBD	μA
		$f_{HFRCO} = 1 \text{ MHz}$, DPLL enabled	—	36	TBD	μA
Coarse trim step size (% of period)	SS_{HFRCO_COARSE}		—	0.8	—	%
Fine trim step size (% of period)	SS_{HFRCO_FINE}		—	0.1	—	%
Period jitter	PJ_{HFRCO}		—	0.2	—	% RMS

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
ADC clock frequency	f _{ADCCLK}		—	—	16	MHz
Throughput rate	f _{ADC RATE}		—	—	1	Msps
Conversion time ¹	t _{ADCCONV}	6 bit	—	7	—	cycles
		8 bit	—	9	—	cycles
		12 bit	—	13	—	cycles
Startup time of reference generator and ADC core	t _{ADCSTART}	WARMUPMODE ⁴ = NORMAL	—	—	5	μs
		WARMUPMODE ⁴ = KEEPIN-STANDBY	—	—	2	μs
		WARMUPMODE ⁴ = KEEPINSLOWACC	—	—	1	μs
SNDR at 1Msps and f _{IN} = 10kHz	SNDR _{ADC}	Internal reference ⁷ , differential measurement	TBD	67	—	dB
		External reference ⁶ , differential measurement	—	68	—	dB
Spurious-free dynamic range (SFDR)	SFDR _{ADC}	1 MSamples/s, 10 kHz full-scale sine wave	—	75	—	dB
Differential non-linearity (DNL)	DNL _{ADC}	12 bit resolution, No missing codes	TBD	—	TBD	LSB
Integral non-linearity (INL), End point method	INL _{ADC}	12 bit resolution	TBD	—	TBD	LSB
Offset error	V _{ADC OFFSETERR}		TBD	0	TBD	LSB
Gain error in ADC	V _{ADCGAIN}	Using internal reference	—	-0.2	TBD	%
		Using external reference	—	-1	—	%
Temperature sensor slope	V _{TS_SLOPE}		—	-1.84	—	mV/°C

Note:

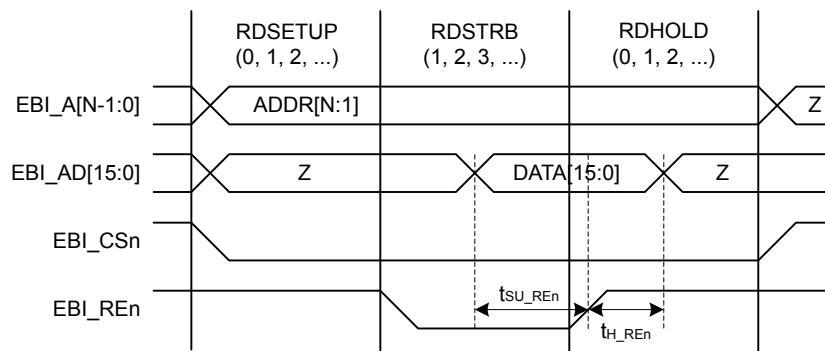
1. Derived from ADCCLK.
2. PSRR is referenced to AVDD when ANASW=0 and to DVDD when ANASW=1 in EMU_PWRCTRL.
3. In ADCn_BIASPROG register.
4. In ADCn_CNTL register.
5. The absolute voltage allowed at any ADC input is dictated by the power rail supplied to on-chip circuitry, and may be lower than the effective full scale voltage. All ADC inputs are limited to the ADC supply (AVDD or DVDD depending on EMU_PWRCTRL_ANASW). Any ADC input routed through the APOR will further be limited by the IOVDD supply to the pin.
6. External reference is 1.25 V applied externally to ADCnEXTREFP, with the selection CONF in the SINGLECTRL_REF or SCANCTRL_REF register field and VREFP in the SINGLECTRLX_VREFSEL or SCANCTRLX_VREFSEL field. The differential input range with this configuration is ± 1.25 V.
7. Internal reference option used corresponds to selection 2V5 in the SINGLECTRL_REF or SCANCTRL_REF register field. The differential input range with this configuration is ± 1.25 V. Typical value is characterized using full-scale sine wave input. Minimum value is production-tested using sine wave input at 1.5 dB lower than full scale.

EBI Read Enable Timing Requirements

Timing applies to both EBI_REn and EBI_NANDREn for all addressing modes and both polarities. All numbers are based on route locations 0,1,2 only (with all EBI alternate functions using the same location at the same time). Timing is specified at 10% and 90% of IOVDD, 25 pF external loading, and slew rate for all GPIO set to 6.

Table 4.40. EBI Read Enable Timing Requirements

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Setup time, from EBI_AD valid to trailing EBI_REn edge	t_{SU_REn}	IOVDD $\geq 1.62\text{ V}$	55	—	—	ns
		IOVDD $\geq 3.0\text{ V}$	36	—	—	ns
Hold time, from trailing EBI_REn edge to EBI_AD invalid	t_{H_REn}	IOVDD $\geq 1.62\text{ V}$	-9	—	—	ns

**Figure 4.7. EBI Read Enable Timing Requirements**

SDIO DDR Mode Timing

Timing is specified for route location 0 at 1.8 V IOVDD with voltage scaling disabled. Slew rate for SD_CLK set to 6, all other GPIO set to 6, DRIVESTRENGTH = STRONG for all pins. SDIO_CTRL_TXDLYMUXSEL = 1. Loading between 5 and 10 pF on all pins or between 10 and 30 pF on all pins.

Table 4.49. SDIO DS Mode Timing (Location 0)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Clock frequency during data transfer	FSD_CLK	Using HFRCO, AUXHFRCO, or USHFRCO	—	—	20	MHz
		Using HFXO	—	—	TBD	MHz
Clock low time	tWL	Using HFRCO, AUXHFRCO, or USHFRCO	22.6	—	—	ns
		Using HFXO	TBD	—	—	ns
Clock high time	tWH	Using HFRCO, AUXHFRCO, or USHFRCO	22.6	—	—	ns
		Using HFXO	TBD	—	—	ns
Clock rise time	tR		1.69	6.52	—	ns
Clock fall time	tF		1.42	4.96	—	ns
Input setup time, CMD valid to SD_CLK	tISU		6	—	—	ns
Input hold time, SD_CLK to CMD change	tIH		1.8	—	—	ns
Output delay time, SD_CLK to CMD valid	tODLY		0	—	16	ns
Output hold time, SD_CLK to CMD change	tOH		0.8	—	—	ns
Input setup time, DAT[0:3] valid to SD_CLK	tISU2X		6	—	—	ns
Input hold time, SD_CLK to DAT[0:3] change	tIH2X		1.5	—	—	ns
Output delay time, SD_CLK to DAT[0:3] valid	tODLY2X		0	—	16	ns
Output hold time, SD_CLK to DAT[0:3] change	tOH2X		0.8	—	—	ns

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PB2	M2	GPIO	PB3	M3	GPIO
PC6	M14	GPIO	VREGVSS	M15 N16	Voltage regulator VSS
VREGSW	M16	DCDC regulator switching node	PB4	N1	GPIO
PB5	N2	GPIO	PB6	N3	GPIO
PD5	N14	GPIO	PD4	N15	GPIO
PC0	P1	GPIO (5V)	PC1	P2	GPIO (5V)
PC2	P3	GPIO (5V)	PA8	P4	GPIO
PA11	P5	GPIO	PA13	P6	GPIO (5V)
PB9	P7	GPIO (5V)	PB12	P8	GPIO
PH2	P9	GPIO (5V)	PH5	P10	GPIO
PH8	P11	GPIO (5V)	PH11	P12	GPIO (5V)
PH13	P13	GPIO (5V)	PD0	P14	GPIO (5V)
PD3	P15	GPIO	PD8	P16	GPIO
PB7	R1	GPIO	PC3	R2	GPIO (5V)
PC5	R3	GPIO	PA9	R4	GPIO
BODEN	R5	Brown-Out Detector Enable. This pin may be left disconnected or tied to AVDD.	RESETn	R6	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.
PB10	R7	GPIO (5V)	PH0	R8	GPIO (5V)
PH3	R9	GPIO (5V)	PH6	R10	GPIO
PH9	R11	GPIO (5V)	PH12	R12	GPIO (5V)
PH14	R13	GPIO (5V)	PH15	R14	GPIO (5V)
PD2	R15	GPIO (5V)	PD7	R16	GPIO
PB8	T1	GPIO	PC4	T2	GPIO
PA7	T3	GPIO	PA10	T4	GPIO
PA12	T5	GPIO (5V)	PA14	T6	GPIO
PB11	T7	GPIO	PH1	T8	GPIO (5V)
PH4	T9	GPIO	PH7	T10	GPIO (5V)
PH10	T11	GPIO (5V)	PB13	T12	GPIO
PB14	T13	GPIO	AVDD	T14	Analog power supply.
PD1	T15	GPIO	PD6	T16	GPIO

Note:

1. GPIO with 5V tolerance are indicated by (5V).
2. The pins PD13, PD14, and PD15 will not be 5V tolerant on all future devices. In order to preserve upgrade options with full hardware compatibility, do not use these pins with 5V domains.

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA15	B1	GPIO	PE14	B2	GPIO
PE12	B3	GPIO	PE8	B4	GPIO
PD11	B5	GPIO	PD9	B6	GPIO
PF8	B7	GPIO	PF6	B8	GPIO
PF14	B9	GPIO (5V)	PF12	B10	GPIO
PF2	B11	GPIO	PF0	B12	GPIO (5V)
PC14	B13	GPIO (5V)	VREGO	B14	Decoupling for 5 V regulator and regulator output. Power for USB PHY in USB-enabled OPNs
PA1	C1	GPIO	PA0	C2	GPIO
PD13	C3	GPIO (5V)	PE10	C4	GPIO
PI8	C5	GPIO (5V)	PI7	C6	GPIO (5V)
PI6	C7	GPIO (5V)	PF5	C8	GPIO
PF15	C9	GPIO (5V)	PF4	C10	GPIO
PF3	C11	GPIO	PC13	C12	GPIO (5V)
PC12	C13	GPIO (5V)	VREGI	C14	Input to 5 V regulator.
PA3	D1	GPIO	PA2	D2	GPIO
PD14	D3	GPIO (5V)	PC11	D12	GPIO (5V)
PC10	D13	GPIO (5V)	PC9	D14	GPIO (5V)
PA5	E1	GPIO	PA4	E2	GPIO
PD15	E3	GPIO (5V)	IOVDD1	E6	Digital IO power supply 1.
VSS	E7 E8 G5 G7 G8 G10 H5 H7 H8 H10 K7 K8	Ground	IOVDD0	E9 F10 J5 J10 K6 K9	Digital IO power supply 0.
PC8	E12	GPIO (5V)	PI5	E13	GPIO (5V)
PI4	E14	GPIO (5V)	PG0	F1	GPIO (5V)
PA6	F2	GPIO	PG1	F3	GPIO (5V)
IOVDD2	F5	Digital IO power supply 2.	PI3	F12	GPIO (5V)
PI2	F13	GPIO (5V)	PI1	F14	GPIO (5V)
PG3	G1	GPIO (5V)	PG4	G2	GPIO (5V)
PG2	G3	GPIO (5V)	PE7	G12	GPIO
PI0	G13	GPIO (5V)	DECUPLE	G14	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.

5.21 Alternate Functionality Overview

A wide selection of alternate functionality is available for multiplexing to various pins. The following table shows the name of the alternate functionality in the first column, followed by columns showing the possible LOCATION bitfield settings and the associated GPIO pin. Refer to [5.20 GPIO Functionality Table](#) for a list of functions available on each GPIO pin.

Note: Some functionality, such as analog interfaces, do not have alternate settings or a LOCATION bitfield. In these cases, the pinout is shown in the column corresponding to LOCATION 0.

Table 5.21. Alternate Functionality Overview

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
ACMP0_O	0: PE13 1: PE2 2: PD6 3: PB11	4: PA6 5: PB0 6: PB2 7: PB3	Analog comparator ACMP0, digital output.
ACMP1_O	0: PF2 1: PE3 2: PD7 3: PA12	4: PA14 5: PB9 6: PB10 7: PA5	Analog comparator ACMP1, digital output.
ACMP2_O	0: PD8 1: PE0 2: PE1 3: PI0	4: PI1 5: PI2	Analog comparator ACMP2, digital output.
ACMP3_O	0: PF0 1: PC15 2: PC14 3: PC13	4: PI4 5: PI5	Analog comparator ACMP3, digital output.
ADC0_EXTN	0: PD7		Analog to digital converter ADC0 external reference input negative pin.
ADC0_EXTP	0: PD6		Analog to digital converter ADC0 external reference input positive pin.
ADC1_EXTN	0: PD7		Analog to digital converter ADC1 external reference input negative pin.
ADC1_EXTP	0: PD6		Analog to digital converter ADC1 external reference input positive pin.
BOOT_RX	0: PF1		Bootloader RX.
BOOT_TX	0: PF0		Bootloader TX.

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
EBI_A10	0: PE3 1: PD6 2: PC10 3: PB10		External Bus Interface (EBI) address output pin 10.
EBI_A11	0: PE4 1: PD7 2: PI6 3: PB11		External Bus Interface (EBI) address output pin 11.
EBI_A12	0: PE5 1: PD8 2: PI7 3: PB12		External Bus Interface (EBI) address output pin 12.
EBI_A13	0: PE6 1: PC7 2: PI8 3: PD0		External Bus Interface (EBI) address output pin 13.
EBI_A14	0: PE7 1: PE2 2: PI9 3: PD1		External Bus Interface (EBI) address output pin 14.
EBI_A15	0: PC8 1: PE3 2: PI10 3: PD2		External Bus Interface (EBI) address output pin 15.
EBI_A16	0: PB0 1: PE4 2: PH4 3: PD3		External Bus Interface (EBI) address output pin 16.
EBI_A17	0: PB1 1: PE5 2: PH5 3: PD4		External Bus Interface (EBI) address output pin 17.
EBI_A18	0: PB2 1: PE6 2: PH6 3: PD5		External Bus Interface (EBI) address output pin 18.
EBI_A19	0: PB3 1: PE7 2: PH7 3: PD6		External Bus Interface (EBI) address output pin 19.
EBI_A20	0: PB4 1: PC8 2: PH8 3: PD7		External Bus Interface (EBI) address output pin 20.
EBI_A21	0: PB5 1: PC9 2: PH9 3: PC7		External Bus Interface (EBI) address output pin 21.
EBI_A22	0: PB6 1: PC10 2: PH10 3: PE4		External Bus Interface (EBI) address output pin 22.

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
SDIO_DAT7	0: PD9 1: PB4		SDIO Data 7.
SDIO_WP	0: PF9 1: PC5 2: PB15 3: PB9		SDIO Write Protect.
TIM0_CC0	0: PA0 1: PF6 2: PD1 3: PB6	4: PF0 5: PC4 6: PA8 7: PA1	Timer 0 Capture Compare input / output channel 0.
TIM0_CC1	0: PA1 1: PF7 2: PD2 3: PC0	4: PF1 5: PC5 6: PA9 7: PA0	Timer 0 Capture Compare input / output channel 1.
TIM0_CC2	0: PA2 1: PF8 2: PD3 3: PC1	4: PF2 5: PA7 6: PA10 7: PA13	Timer 0 Capture Compare input / output channel 2.
TIM0_CDTI0	0: PA3 1: PC13 2: PF3 3: PC2	4: PB7	Timer 0 Complimentary Dead Time Insertion channel 0.
TIM0_CDTI1	0: PA4 1: PC14 2: PF4 3: PC3	4: PB8	Timer 0 Complimentary Dead Time Insertion channel 1.
TIM0_CDTI2	0: PA5 1: PC15 2: PF5 3: PC4	4: PB11	Timer 0 Complimentary Dead Time Insertion channel 2.
TIM1_CC0	0: PC13 1: PE10 2: PB0 3: PB7	4: PD6 5: PF2 6: PF13 7: PI6	Timer 1 Capture Compare input / output channel 0.
TIM1_CC1	0: PC14 1: PE11 2: PB1 3: PB8	4: PD7 5: PF3 6: PF14 7: PI7	Timer 1 Capture Compare input / output channel 1.
TIM1_CC2	0: PC15 1: PE12 2: PB2 3: PB11	4: PC13 5: PF4 6: PF15 7: PI8	Timer 1 Capture Compare input / output channel 2.
TIM1_CC3	0: PC12 1: PE13 2: PB3 3: PB12	4: PC14 5: PF12 6: PF5 7: PI9	Timer 1 Capture Compare input / output channel 3.
TIM2_CC0	0: PA8 1: PA12 2: PC8 3: PF2	4: PB6 5: PC2 6: PG8 7: PG5	Timer 2 Capture Compare input / output channel 0.

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
U0_TX	0: PF6 1: PE0 2: PA3 3: PC14	4: PC4 5: PF1 6: PD7	UART0 Transmit output. Also used as receive input in half duplex communication.
U1_CTS	0: PC14 1: PF9 2: PB11 3: PE4	4: PC4 5: PH13	UART1 Clear To Send hardware flow control input.
U1_RTS	0: PC15 1: PF8 2: PB12 3: PE5	4: PC5 5: PH14	UART1 Request To Send hardware flow control output.
U1_RX	0: PC13 1: PF11 2: PB10 3: PE3	4: PE13 5: PH12	UART1 Receive input.
U1_TX	0: PC12 1: PF10 2: PB9 3: PE2	4: PE12 5: PH11	UART1 Transmit output. Also used as receive input in half duplex communication.
US0_CLK	0: PE12 1: PE5 2: PC9 3: PC15	4: PB13 5: PA12 6: PG14	USART0 clock input / output.
US0_CS	0: PE13 1: PE4 2: PC8 3: PC14	4: PB14 5: PA13 6: PG15	USART0 chip select input / output.
US0_CTS	0: PE14 1: PE3 2: PC7 3: PC13	4: PB6 5: PB11 6: PH0	USART0 Clear To Send hardware flow control input.
US0_RTS	0: PE15 1: PE2 2: PC6 3: PC12	4: PB5 5: PD6 6: PH1	USART0 Request To Send hardware flow control output.
US0_RX	0: PE11 1: PE6 2: PC10 3: PE12	4: PB8 5: PC1 6: PG13	USART0 Asynchronous Receive. USART0 Synchronous mode Master Input / Slave Output (MISO).
US0_TX	0: PE10 1: PE7 2: PC11 3: PE13	4: PB7 5: PC0 6: PG12	USART0 Asynchronous Transmit. Also used as receive input in half duplex communication. USART0 Synchronous mode Master Output / Slave Input (MOSI).
US1_CLK	0: PB7 1: PD2 2: PF0 3: PC15	4: PC3 5: PB11 6: PE5	USART1 clock input / output.
US1_CS	0: PB8 1: PD3 2: PF1 3: PC14	4: PC0 5: PE4 6: PB2	USART1 chip select input / output.

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
US5_RX	0: PE9 1: PA7 2: PB1 3: PH11		USART5 Asynchronous Receive. USART5 Synchronous mode Master Input / Slave Output (MISO).
US5_TX	0: PE8 1: PA6 2: PF15 3: PH10		USART5 Asynchronous Transmit. Also used as receive input in half duplex communication. USART5 Synchronous mode Master Output / Slave Input (MOSI).
USB_DM	0: PF10		USB D- pin.
USB_DP	0: PF11		USB D+ pin.
USB_ID	0: PF12		USB ID pin.
USB_VBUSEN	0: PF5		USB 5 V VBUS enable.
VDAC0_EXT	0: PD6		Digital to analog converter VDAC0 external reference input pin.
VDAC0_OUT0 / OPA0_OUT	0: PB11		Digital to Analog Converter DAC0 output channel number 0.
VDAC0_OUT0ALT / OPA0_OUTALT	0: PC0 1: PC1 2: PC2 3: PC3	4: PD0	Digital to Analog Converter DAC0 alternative output for channel 0.
VDAC0_OUT1 / OPA1_OUT	0: PB12		Digital to Analog Converter DAC0 output channel number 1.
VDAC0_OUT1ALT / OPA1_OUTALT	0: PC12 1: PC13 2: PC14 3: PC15	4: PD1	Digital to Analog Converter DAC0 alternative output for channel 1.
WTIM0_CC0	0: PE4 1: PA6 2: PG2 3: PG8	4: PC15 5: PB0 6: PB3 7: PC1	Wide timer 0 Capture Compare input / output channel 0.
WTIM0_CC1	0: PE5 1: PD13 2: PG3 3: PG9	4: PF0 5: PB1 6: PB4 7: PC2	Wide timer 0 Capture Compare input / output channel 1.

Table 5.29. CSEN Bus and Pin Mapping

	Port	Port	Port
APORT1Y	APORT1X	APORT4Y	APORT4X
BUSCY	BUSCX	BUSDX	BUSBY
PF15	Bus	PF15	PF15
PF14	CH31	PF14	PF14
PF13	CH30	PF13	PF13
PF12	CH29	PF12	PF12
PF11	CH28	PF11	PF11
PF10	CH27	PF10	PF10
PF9	CH26	PF9	PF9
PF8	CH25	PF8	PF8
PF7	CH24	PF7	PF7
PF6	CH23	PF6	PF6
PF5	CH22	PF5	PF5
PF4	CH21	PF4	PF4
PF3	CH20	PF3	PF3
PF2	CH19	PF2	PF2
PF1	CH18	PF1	PF1
PF0	CH17	PF0	PF0
PE15	CH16	PE15	PE15
PE14	CH15	PE14	PE14
PE13	CH14	PE13	PE13
PE12	CH13	PE12	PE12
PE11	CH12	PE11	PE11
PE10	CH11	PE10	PE10
PE9	CH10	PE9	PE9
PE8	CH9	PE8	PE8
PE7	CH8	PE7	PE7
PE6	CH7	PE6	PE6
PE5	CH6	PE5	PE5
PE4	CH5	PE4	PE4
PE3	CH4	PE3	PE4
PE2	CH3	PE2	PA3
PE1	CH2	PE1	PA2
PE0	CH1	PE0	PA1
PE0	CH0	PE0	PA0

Table 5.30. IDAC0 Bus and Pin Mapping

Port	Port	Port	Port
PA15	PA14	PA13	PA13
PA12	PA12	PA11	PA11
PA10	PA10	PA9	PA9
PA8	PA8	PA8	PA8
PA7	PA7	PA7	PA7
PA6	PA6	PA6	PA6
PA5	PA5	PA5	PA5
PA4	PA4	PA4	PA4
PA3	PA3	PA3	PA3
PA2	PA2	PA2	PA2
PA1	PA1	PA1	PA1
PA0	PA0	PA0	PA0

8.2 BGA120 PCB Land Pattern

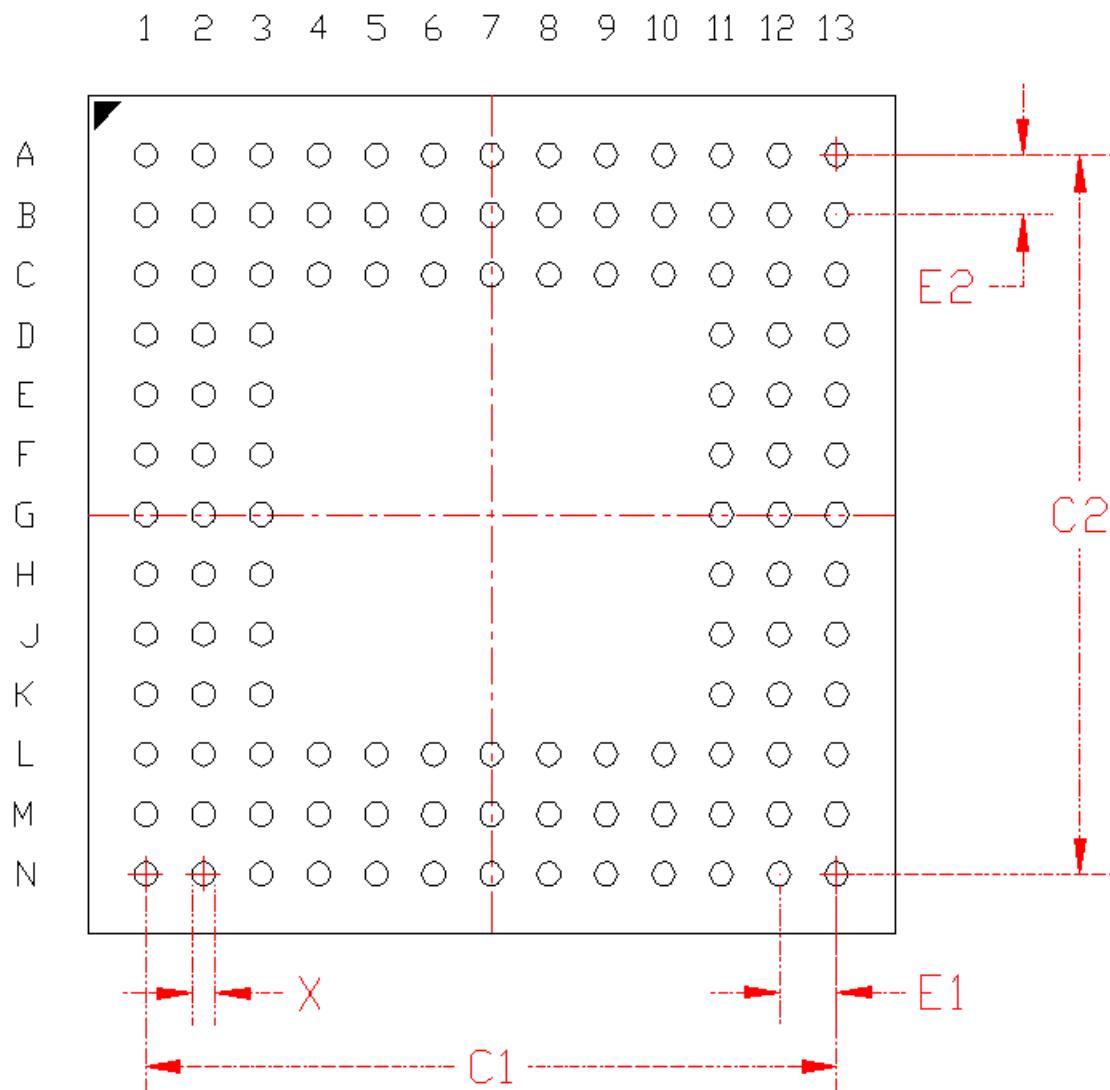


Figure 8.2. BGA120 PCB Land Pattern Drawing

10. TQFP100 Package Specifications

10.1 TQFP100 Package Dimensions

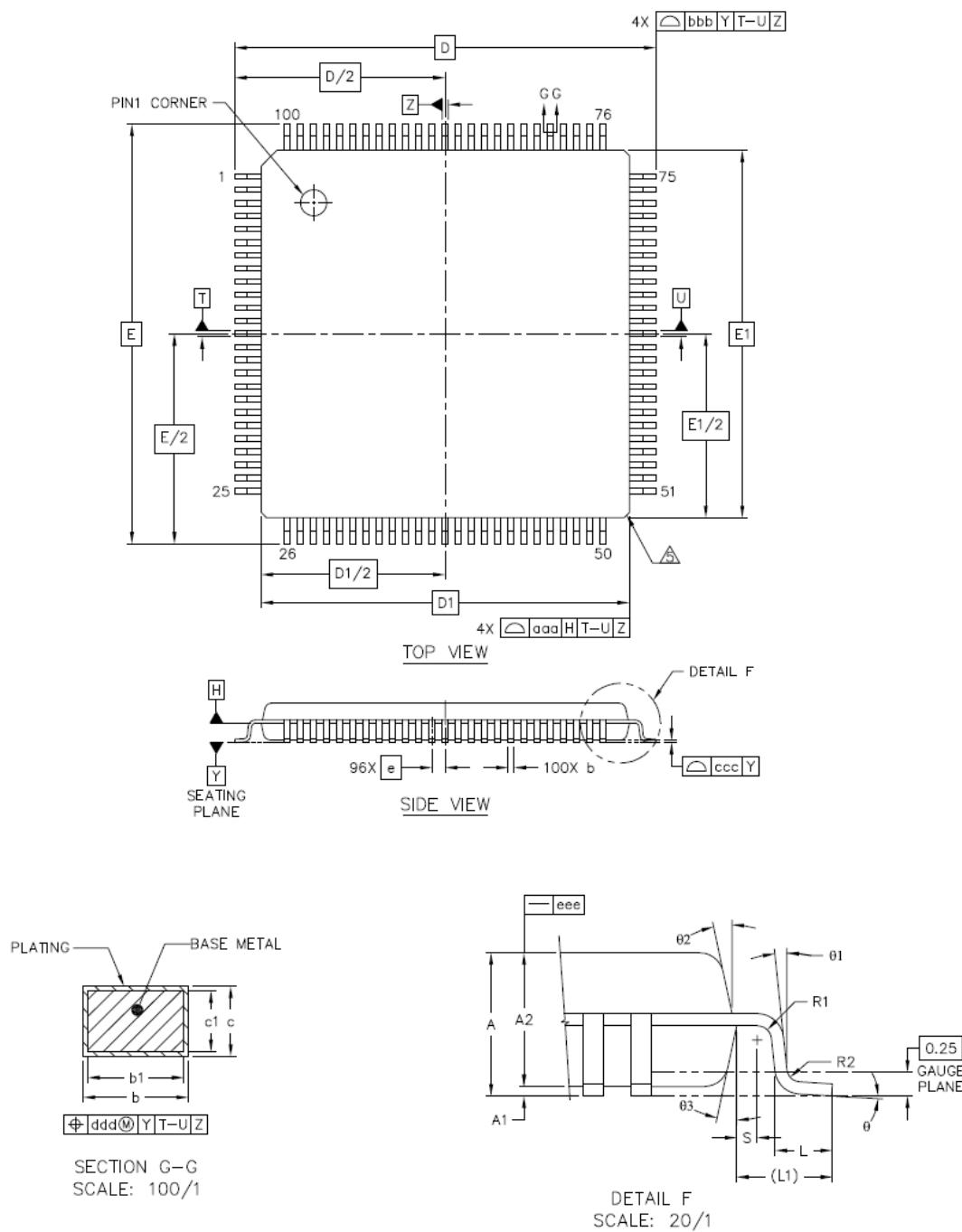


Figure 10.1. TQFP100 Package Drawing

13. Revision History

Revision 0.6

March, 2018

- Removed "Confidential" watermark.
- Updated [4.1 Electrical Characteristics](#) and [4.2 Typical Performance Curves](#) with latest characterization data.

Revision 0.2

October, 2017

- Updated memory maps to latest formatting and to include all peripherals.
- Updated all electrical specifications tables with latest characterization results.
- **Absolute Maximum Ratings Table:**
 - Removed redundant I_{VSSMAX} line.
 - Added footnote to clarify V_{DIGPIN} specification for 5V tolerant GPIO.
- **General Operating Conditions Table:**
 - Removed dV_{DD} specification and redundant footnote about shorting VREGVDD and AVDD together.
 - Added footnote about IOVDD voltage restriction when CSEN peripheral is used with chopping enabled.
- **Flash Memory Characteristics Table:** Added timing measurement clarification for Device Erase and Mass Erase.
- **Analog to Digital Converter (ADC) Table:**
 - Added header text for general specification conditions.
 - Added footnote for clarification of input voltage limits.
- Minor typographical corrections, including capitalization, mis-spellings and punctuation marks, throughout document.
- Minor formatting and styling updates, including table formats, TOC location, and boilerplate information throughout document.

Revision 0.1

April 27th, 2017

Initial release.